











uA78M05, uA78M06, uA78M08 uA78M09, uA78M10, uA78M12, uA78M33

SLVS059T - JUNE 1976-REVISED JANUARY 2015

### µA78Mxx Positive-Voltage Regulators

#### **Features**

- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection
- High Power-Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation

#### Applications

- **On-Card Regulation**
- Portable Devices
- Computing & Servers
- **Telecommunications**

#### 3 Description

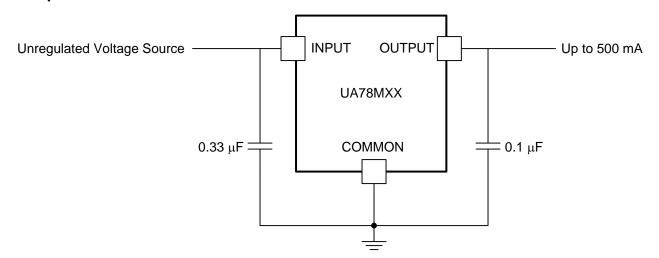
This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. The applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SOT-223 (3)	6.50 mm x 3.50 mm
UA78Mxx	TO-220 (3) 10.16 mm x 8.82	
	TO-252 (3)	6.60 mm x 6.10 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### **Simplified Schematic**





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#### 5 Revision History

# Changes from Revision S (May 2013) to Revision T Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section. Changes from Revision R (February 2013) to Revision S Page Removed Ordering Information table.

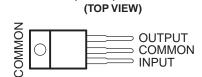
# Changes from Revision Q (April 2010) to Revision R Page

Removed obsolete part information from document.

Submit Documentation Feedback

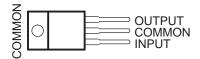


#### 6 Pin Configuration and Functions

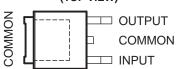


KC (TO-220) PACKAGE

#### KCS (TO-220) PACKAGE (TOP VIEW)

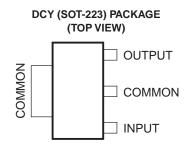


#### KVU (TO-252) PACKAGE (TOP VIEW)



# KTP (PowerFLEX /TO-252\*) PACKAGE (TOP VIEW) OUTPUT COMMON INPUT

\* Complies with JEDEC TO-252, variation AC



#### **Pin Functions**

	PIN	TYPE	DESCRIPTION			
NAME	NO.	IIFE	DESCRIPTION			
COMMON	2	_	Ground			
INPUT	1	I	Supply Input			
OUTPUT	3	0	Voltage Output			



#### 7 Specifications

#### 7.1 Absolute Maximum Ratings

over virtual junction temperature range (unless otherwise noted) (1)

	, ,			
		MIN	MAX	UNIT
$V_{I}$	Input voltage		35	V
$T_{J}$	Operating virtual junction temperature		150	°C
T <sub>stg</sub>	Storage temperature range	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	2500	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	2000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

#### 7.3 Recommended Operating Conditions

	' 5		MIN	MAX	UNIT
		uA78M33	5.3	25	
		uA78M05	7	25	
VI	uA78M06	uA78M06	8	25	
		10.5	25	\/	
		uA78M09	11.5	26	V
		uA78M10	12.5	28	
		uA78M12	14.5	30	
		uA78M15	17.5	30	
Io	Output current			500	mA
т	Operating virtual junction temperature	uA78MxxC	0	125	Ŝ
TJ	Operating virtual junction temperature	uA78MxxI	-40	125	C

#### 7.4 Thermal Information

			UA78Mxx					
	THERMAL METRIC <sup>(1)</sup>	DCY	KC	KCS	KTP	KVU	UNIT	
		3 PINS	3 PINS	3 PINS	3 PINS	3 PINS		
$R_{\thetaJA}$	Junction-to-ambient thermal resistance	53	19	19	28	30.3		
R <sub>θJC(to</sub> p)	Junction-to-case (top) thermal resistance	30.6	17	17	19	_	°C/W	
$R_{\theta JC(b}$ ot)	Junction-to-case (bottom) thermal resistance	_	3	3	1.4	_		

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



#### 7.5 Electrical Characteristics — uA78M33C

at specified virtual junction temperature, V<sub>1</sub> = 8 V, I<sub>0</sub> = 350 mA, T<sub>1</sub> = 25°C (unless otherwise noted)

PARAMETER0	TEST CONDITIONS <sup>(1)</sup>		uA <sup>-</sup>	UNIT			
PARAMETERU	TEST CONDITIONS.			MIN	TYP	MAX	Oldii
Output voltage <sup>(2)</sup>	$I_{O} = 5 \text{ mA to } 350$	mA,		3.2	3.3	3.4	V
Output voltage	$V_1 = 8 \text{ V to } 20 \text{ V}$		$T_J = 0$ °C to 125°C	3.1	3.3	3.5	V
Innut voltogo regulation	1 200 m A		$V_1 = 5.3 \text{ V to } 25 \text{ V}$		9	100	mV
Input voltage regulation	I <sub>O</sub> = 200 mA		$V_{I} = 8 \text{ V to } 25 \text{ V}$		3	50	mv
Dinnle rejection	$V_1 = 8 \text{ V to } 18 \text{ V},$		$I_{O} = 100 \text{ mA}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	62			dB
Rippie rejection	ipple rejection $f = 120 \text{ Hz}$		I <sub>O</sub> = 300 mA	62	80		uБ
Output voltage regulation	V <sub>I</sub> = 8 V,		I <sub>O</sub> = 5 mA to 500 mA		20	100	mV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,		$T_J = 0$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 k	:Hz			40	200	μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Dies summent about	I <sub>O</sub> = 200 mA,	$V_I = 8 \text{ V to } 25 \text{ V},$	$T_J = 0$ °C to 125°C			0.8	A
Bias current change	$I_{O} = 5 \text{ mA to } 350$	mA,	$T_J = 0$ °C to 125°C		0.5	mA	
Short-circuit output current	V <sub>I</sub> = 35 V				300		mA
Peak output current					700		mA

All characteristics are measured with a 0.33-µF capacitor across the input and a 0.1-µF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

#### 7.6 Electrical Characteristics — uA78M33I

at specified virtual junction temperature, V<sub>I</sub> = 8 V, I<sub>O</sub> = 350 mA, T<sub>J</sub> = 25°C (unless otherwise noted)

DADAMETED	TEST CONDITIONS <sup>(1)</sup>		uA	78M33		UNIT	
PARAMETER		IEST CONDIT	ions	MIN	TYP	MAX	UNII
Output voltage <sup>(2)</sup>	I <sub>O</sub> = 5 mA to 350 m	nA,		3.2	3.3	3.4	V
Output Voltage V	$V_1 = 8 \text{ V to } 20 \text{ V}$		$T_J = -40$ °C to 125°C	3.1	3.3	3.5	V
lanut valtage regulation	1 200 m A		$V_1 = 5.3 \text{ V to } 25 \text{ V}$		9	100	mV
Input voltage regulation	$I_{O} = 200 \text{ mA}$		$V_I = 8 \text{ V to } 25 \text{ V}$		3	50	IIIV
Ripple rejection	Ripple rejection $V_I = 8 \text{ V to } 18 \text{ V,}$ f = 120  Hz		$I_O = 100 \text{ mA}, T_J = -40^{\circ}\text{C to}$ 125°C	62			dB
			I <sub>O</sub> = 300 mA	62	80		
Output voltage regulation	$V_{I} = 8 V,$		$I_O = 5 \text{ mA to } 500 \text{ mA}$		20	100	mV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,		$T_J = -40$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kl	Нz			40	200	μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Dies surrent change	$I_{O} = 200 \text{ mA},$	$V_1 = 8 V \text{ to } 25 V,$	$T_J = -40$ °C to 125°C			8.0	mA
Bias current change	$I_O = 5$ mA to 350 mA,		$T_J = -40$ °C to 125°C			0.5	ША
Short-circuit output current	V <sub>I</sub> = 35 V				300		mA
Peak output current		·	·		700		mA

All characteristics are measured with a 0.33-µF capacitor across the input and a 0.1-µF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately. This specification applies only for dc power dissipation permitted by *Absolute Maximum Ratings*.

This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.



#### 7.7 Electrical Characteristics — uA78M05C

at specified virtual junction temperature, V<sub>I</sub> = 10 V, I<sub>O</sub> = 350 mA, T<sub>J</sub> = 25°C (unless otherwise noted)

DADAMETED	TEO	TEST CONDITIONS <sup>(1)</sup>			uA78M05C		
PARAMETER	TEST CONDITIONS.			TYP	MAX	UNIT	
Output voltage <sup>(2)</sup>	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$		4.8	5	5.2	V	
Output voltage 7	$V_1 = 7 \text{ V to } 20 \text{ V}$	$T_J = 0$ °C to 125°C	4.75		5.25	V	
lanut valtana namulatian		$V_I = 7 V \text{ to } 25 V$		3	100	\/	
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 8 V to 25 V		1	50	mV	
Dinale rejection	$V_{I} = 8 \text{ V to } 18 \text{ V},$	$I_{O} = 100 \text{ mA}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	62			dB	
Ripple rejection	f = 120 Hz	I <sub>O</sub> = 300 mA	62	80		uБ	
Output valtage regulation	$I_O = 5 \text{ mA to } 500 \text{ mA}$			20	100		
Output voltage regulation	$I_O = 5 \text{ mA to } 200 \text{ mA}$			10	50	mV	
Temperature coefficient of output voltage	$I_O = 5 \text{ mA},$	$T_J = 0$ °C to 125°C		-1		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV	
Dropout voltage				2		V	
Bias current				4.5	6	mA	
Dies sument shanns	$I_O = 200 \text{ mA}, V_I = 8 \text{ V to } 25$	I <sub>O</sub> = 200 mA, V <sub>I</sub> = 8 V to 25 V, T <sub>J</sub> = 0°C to 125°C			0.8	A	
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C			0.5	mA	
Short-circuit output current	V <sub>I</sub> = 35 V			300		mA	
Peak output current				0.7		Α	

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

#### 7.8 Electrical Characteristics — uA78M05I

at specified virtual junction temperature,  $V_1 = 10 \text{ V}$ ,  $I_0 = 350 \text{ mA}$ ,  $T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

DADAMETED	TEST CONDITIONS <sup>(1)</sup>		u/	478M0	51	LINUT
PARAMETER	TEST CO	ONDITIONS ***	MIN	TYP	MAX	UNIT
Output voltage <sup>(2)</sup>	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$		4.8	5	5.2	V
Output voitage (=/	$V_1 = 7 \text{ V to } 20 \text{ V}$	$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	4.75		5.25	V
land to the second stine	J 200 A	V <sub>I</sub> = 7 V to 25 V		3	100	\/
Input voltage regulation	$I_{O} = 200 \text{ mA}$	V <sub>I</sub> = 8 V to 25 V		1	50	mV
Dinale rejection	V <sub>I</sub> = 8 V to 18 V,	$I_O = 100 \text{ mA}, T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C}$	62			5
Ripple rejection	f = 120 Hz	I <sub>O</sub> = 300 mA	62	80		dB
Output voltage	I <sub>O</sub> = 5 mA to 500 mA			20	100	\/
regulation	I <sub>O</sub> = 5 mA to 200 mA	mA		10	50	mV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,	$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Dies sument about	$I_0 = 200 \text{ mA}, \qquad V_1 = 8 \text{ V to } 25 \text{ V},$	$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			0.8	A
Bias current change	I <sub>O</sub> = 5 mA to 350 mA,	$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			0.5	mA
Short-circuit output current	V <sub>I</sub> = 35 V			300		mA
Peak output current				0.7		Α

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.



#### 7.9 Electrical Characteristics — uA78M06C

at specified virtual junction temperature,  $V_1 = 11 \text{ V}$ ,  $I_0 = 350 \text{ mA}$ ,  $T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

DADAMETED	TEST CONDITIONS <sup>(1)</sup>			uA	uA78M06C		
PARAMETER	TEST CONDITIONS "				TYP	MAX	UNIT
Output voltage <sup>(2)</sup>	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	$V_1 = 8 \text{ V to } 21 \text{ V}$		5.75	6	6.25	V
Output voltage V	1 <sub>0</sub> = 5 mA to 350 mA,	V <sub>1</sub> = 0 V 10 21 V	$T_J = 0$ °C to 125°C	5.7		6.3	V
Input voltage regulation	1 200 m A	V <sub>I</sub> = 8 V to 25 V			5	100	mV
Input voltage regulation	I <sub>O</sub> = 200 mA	$V_{I} = 9 V \text{ to } 25 V$			1.5	50	IIIV
Ripple rejection	V <sub>I</sub> = 8 V to 18 V,	f = 120 Hz	$I_{O} = 100 \text{ mA},$ $T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	59			dB
		$I_{O} = 300 \text{ mA}$	59	80			
Output voltage regulation	$I_O = 5$ mA to 500 mA				20	120	m\/
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	60	mV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				45		μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Diag surrent change	$V_{I} = 9 V \text{ to } 25 V,$	I <sub>O</sub> = 200 mA,	$T_J = 0$ °C to 125°C			0.8	A
Bias current change	$I_O = 5$ mA to 350 mA,	T <sub>J</sub> = 0°C to 125°C				0.5	mA
Short-circuit output current	V <sub>I</sub> = 35 V				270		mA
Peak output current					0.7		Α

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

#### 7.10 Electrical Characteristics — uA78M08C

at specified virtual junction temperature,  $V_1 = 14 \text{ V}$ ,  $I_0 = 350 \text{ mA}$ ,  $T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>(1)</sup>		uA	uA78M08C		UNIT
PARAIVIETER		TEST CONDITIONS.		MIN	TYP	MAX	UNII
Output voltage <sup>(2)</sup>	V = 10 5 V to 22 V	l − 5 mΛ to 350 mΛ		7.7	8	8.3	V
Output Voltage V	$V_I = 10.5 \text{ V to } 23 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	7.6		8.4	V
Input voltage regulation	L = 200 mA	$V_I = 10.5 \text{ V to } 25 \text{ V}$			6	100	mV
Input voltage regulation	I <sub>O</sub> = 200 mA	$V_{I} = 11 \text{ V to } 25 \text{ V}$			2	50	IIIV
Dipple rejection	$V_I = 11 \text{ V to } 21.5 \text{ V},$	$I_O = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Ripple rejection	f = 120 Hz	$I_{O} = 300 \text{ mA}$		56	80		uБ
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	160	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	80	IIIV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				52		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Dies sument shares	V <sub>I</sub> = 10.5 V to 25 V,	I <sub>O</sub> = 200 mA,	$T_J = 0$ °C to 125°C			8.0	Λ
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V <sub>I</sub> = 35 V				250		mA
Peak output current		·	<u>-</u>		0.7		Α

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by *Absolute Maximum Ratings*.



#### 7.11 Electrical Characteristics — uA78M09C

at specified virtual junction temperature, V<sub>I</sub> = 16 V, I<sub>O</sub> = 350 mA, T<sub>J</sub> = 25°C (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)		uA	78M09	C	LINUT
PARAMETER		IEST CONDITIONS		MIN	TYP	MAX	UNIT
Output voltage <sup>(2)</sup>	V <sub>I</sub> = 11.5 V to 24 V,	$I_0 = 5 \text{ mA to } 350 \text{ mA}$		8.6	9	9.4	V
Output voltage	V <sub>1</sub> = 11.5 V tO 24 V,	10 = 3 IIIA 10 330 IIIA	$T_J = 0$ °C to 125°C	8.5		9.5	V
Input voltage regulation	L = 200 mA	$V_I = 11.5 \text{ V to } 26 \text{ V}$			6	100	mV
Input voltage regulation	I <sub>O</sub> = 200 mA	$V_I = 12 \text{ V to } 26 \text{ V}$			2	50	mv
Dipple rejection	V <sub>I</sub> = 13 V to 23 V,	$I_{O} = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Ripple rejection	f = 120 Hz	$I_{O} = 300 \text{ mA}$		56	80		uБ
Output voltage regulation	$I_O = 5$ mA to 500 mA				25	180	m\/
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	90	mV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Dies current change	$V_I = 11.5 \text{ V to } 26 \text{ V},$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			8.0	mA
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	IIIA
Short-circuit output current	V <sub>I</sub> = 35 V				250		mA
Peak output current					0.7		Α

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

#### 7.12 Electrical Characteristics — uA78M10C

at specified virtual junction temperature,  $V_1 = 17 \text{ V}$ ,  $I_0 = 350 \text{ mA}$ ,  $T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>(1)</sup>		uA78M10C			LINUT
PARAIVIETER		TEST CONDITIONS.		MIN	TYP	MAX	UNIT
Output voltage <sup>(2)</sup>	V = 12 5 V to 25 V	l − 5 mΛ to 250 mΛ		9.6	10	10.4	V
Output Voltage V	$V_I = 12.5 \text{ V to } 25 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	9.5		10.5	V
lanut valtage regulation	1 200 m A	$V_I = 12.5 \text{ V to } 28 \text{ V}$			7	100	mV
Input voltage regulation	I <sub>O</sub> = 200 mA	$V_1 = 14 \text{ V to } 28 \text{ V}$			2	50	IIIV
Dinale rejection	V <sub>I</sub> = 15 V to 25 V,	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	59			dB
Ripple rejection	f = 120 Hz	$I_O = 300 \text{ mA}$		55	80		uБ
Output valta as va sulation	$I_O = 5$ mA to 500 mA				25	200	\/
Output voltage regulation	I <sub>O</sub> = 5 mA to 200 mA				10	100	mV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,	T <sub>J</sub> = 0°C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				64		μV
Dropout voltage					2		V
Bias current					4.7	6	mA
D'accommendation and	V <sub>I</sub> = 12.5 V to 28 V,	I <sub>O</sub> = 200 mA,	$T_J = 0$ °C to 125°C			0.8	1
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V <sub>I</sub> = 35 V				245		mA
Peak output current					0.7		Α

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.



#### 7.13 Electrical Characteristics — uA78M12C

at specified virtual junction temperature,  $V_1 = 19 \text{ V}$ ,  $I_0 = 350 \text{ mA}$ ,  $T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)		uA	78M12	2C	LINUT
PARAMETER		1E21 CONDITION2(1)		MIN	TYP	MAX	UNIT
Output voltage <sup>(2)</sup>	V <sub>I</sub> = 14.5 V to 27 V,	$I_0 = 5 \text{ mA to } 350 \text{ mA}$		11.5	12	12.5	V
Output voltage 7	$V_1 = 14.5 \text{ V to } 27 \text{ V},$	1 <sub>0</sub> = 5 IIIA to 350 IIIA	$T_J = 0$ °C to 125°C	11.4		12.6	V
Input voltage regulation	I <sub>O</sub> = 200 mA	$V_I = 14.5 \text{ V to } 30 \text{ V}$			8	100	mV
input voltage regulation	10 = 200 IIIA	$V_I = 16 \text{ V to } 30 \text{ V}$			2	50	IIIV
Ripple rejection	$V_{I} = 15 \text{ V to } 25 \text{ V},$	$I_O = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	55			dB
Ripple rejection	f = 120 Hz	I <sub>O</sub> = 300 mA		55	80		uБ
Output voltage regulation	$I_O = 5$ mA to 500 mA				25	240	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	120	IIIV
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Diag gurrant shangs	$V_I = 14.5 \text{ V to } 30 \text{ V},$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			8.0	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V <sub>I</sub> = 35 V				240		mA
Peak output current					0.7		Α

<sup>(1)</sup> All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T<sub>J</sub> as close to T<sub>A</sub> as possible. Thermal effects must be taken into account separately.

#### 7.14 Typical Characteristics

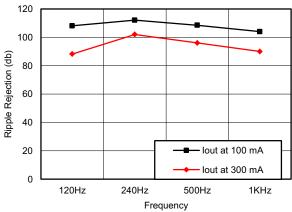


Figure 1. Ripple Rejection vs Frequency V\_INPUT = 8 V to 18 V, TA = 25°C

<sup>(2)</sup> This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

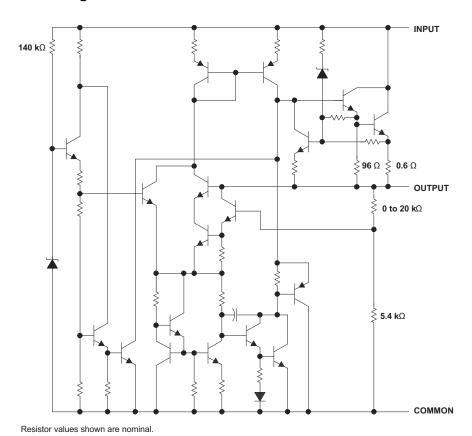


#### 8 Detailed Description

#### 8.1 Overview

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. The applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

#### 8.2 Functional Block Diagram



#### 8.3 Feature Description

- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection
- High Power-Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation

#### 8.4 Device Functional Modes

#### 8.4.1 Fixed-Output Mode

These devices are available in fixed-output voltages. See the orderable part list for the desired output.



#### 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The UA78Mxx devices are ideal for use as linear regulators with few external components needed for a working design. They are also useful for attenuating power supply noise.

#### 9.2 Typical Application

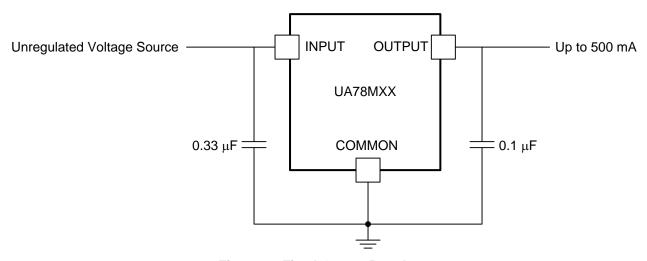


Figure 2. Fixed-Output Regulator

#### 9.2.1 Design Requirements

An 0.33-µF decoupling capacitor on the input and a 0.1-µF decoupling capacitor on the output are recommended for the UA78Mxx to behave as close to datasheet specifications as possible.

#### 9.2.2 Detailed Design Procedure

The customer's end application will determine how the schematic for UA78Mxx is designed. For example, if there is a load connected to a negative voltage as its ground, a clamp diode may be necessary on the output. In the event of an input short circuit or another case where the output voltage can be higher than the input, a diode shunt can be connected across the device with the anode at the output and cathode at the input



#### **Typical Application (continued)**

#### 9.2.3 Application Curves

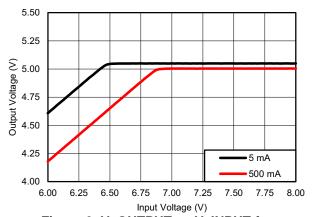


Figure 3. V\_OUTPUT vs V\_INPUT for  $I_{OUTPUT} = 5$  mA and 500 mA (25°C)



#### 10 Power Supply Recommendations

See *Recommended Operating Conditions* for the recommended power supply voltages for each variation of the UA78Mxx. Different orderable part numbers will be able to tolerate different levels of voltage. It is also recommended to have a decoupling capacitor on the output to limit noise on the input.

#### 11 Layout

#### 11.1 Layout Guidelines

Keep trace widths large enough to eliminate problematic IxR voltage drops at the input and output terminals. Input decoupling capacitors should be placed as close to the UA78MXX as possible.

#### 11.2 Layout Example

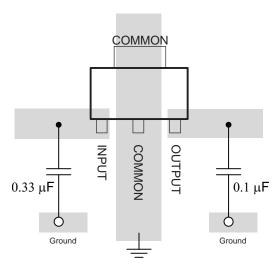


Figure 4. Layout Diagram



#### 12 Device and Documentation Support

#### 12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
uA78M05	Click here	Click here	Click here	Click here	Click here
uA78M06	Click here	Click here	Click here	Click here	Click here
uA78M08	Click here	Click here	Click here	Click here	Click here
uA78M09	Click here	Click here	Click here	Click here	Click here
uA78M10	Click here	Click here	Click here	Click here	Click here
uA78M12	Click here	Click here	Click here	Click here	Click here
uA78M33	Click here	Click here	Click here	Click here	Click here

#### 12.2 Trademarks

All trademarks are the property of their respective owners.

#### 12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

#### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN78MCDCYR	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCYG3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCYR	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M05C	Samples
UA78M05IDCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samples
UA78M05IDCYG3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samples
UA78M05IDCYR	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samples
UA78M05IDCYRG3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samples
UA78M05IKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	78M05I	Samples
UA78M06CKVURG3	LIFEBUY	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M06C	
UA78M08CDCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CDCYG3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CDCYR	LIFEBUY	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	
UA78M08CKVURG3	LIFEBUY	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M08C	
UA78M09CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M09C	Samples
UA78M10CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M10C	Samples
UA78M12CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M12C	Samples
UA78M33CDCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYG3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
UA78M33CDCYR	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CKCS	LIFEBUY	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M33C	
UA78M33CKCSE3	LIFEBUY	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M33C	
UA78M33CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M33C	Samples
UA78M33IKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	78M33I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF UA78M:

Automotive : UA78M-Q1

NOTE: Qualified Version Definitions:

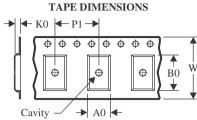
• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M05CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M05CDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M06CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M08CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M08CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M09CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M12CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3



#### **PACKAGE MATERIALS INFORMATION**

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M33CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2



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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UA78M05CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M05CDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M05CKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M05CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M05IDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M05IDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M05IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M05IKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M06CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M08CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M08CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M09CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M10CKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M10CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M12CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M33CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M33CDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M33CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0



#### **PACKAGE MATERIALS INFORMATION**

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	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	UA78M33IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
ĺ	UA78M33IKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0



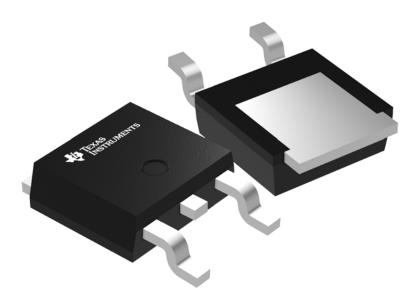
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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
UA78M05CDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05CDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05IDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05IDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M08CDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M08CDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M33CDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M33CDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M33CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M33CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M33CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M33CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6

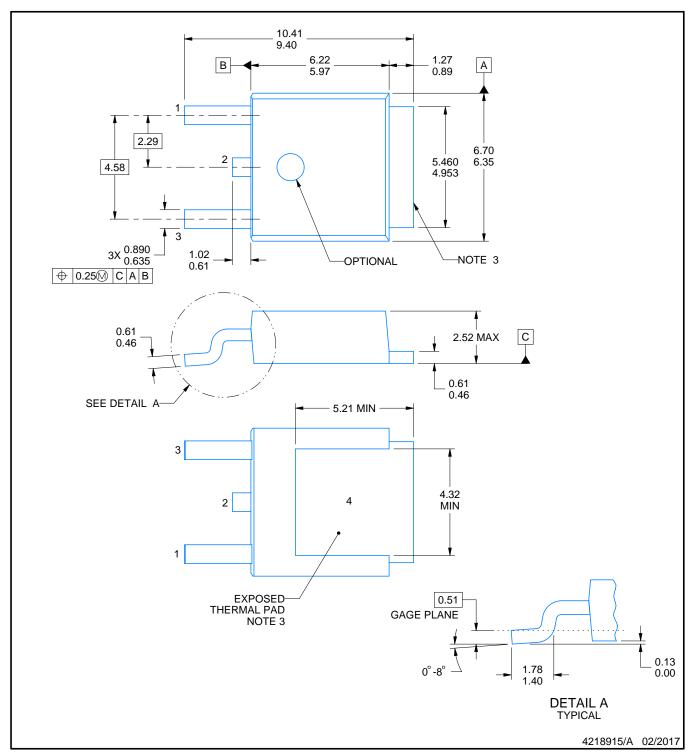


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4205521-2/E







#### NOTES:

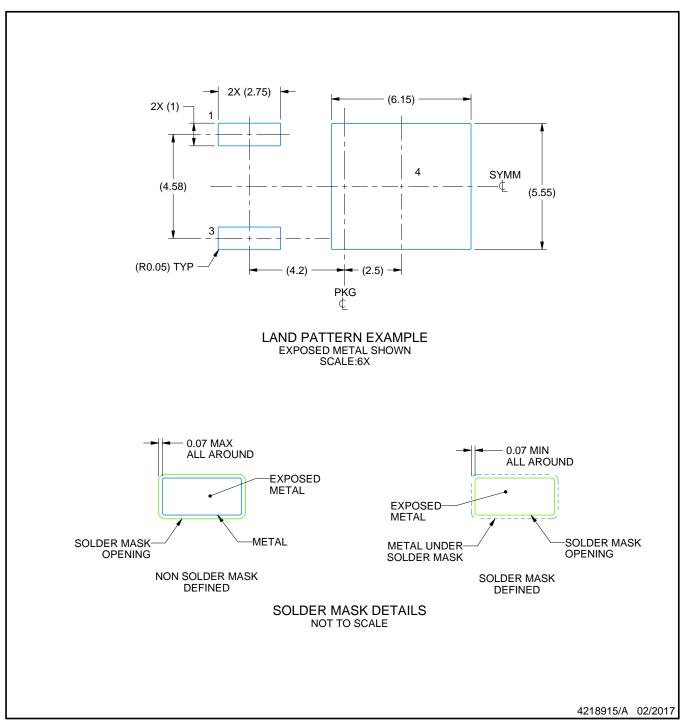
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Shape may vary per different assembly sites.

  4. Reference JEDEC registration TO-252.

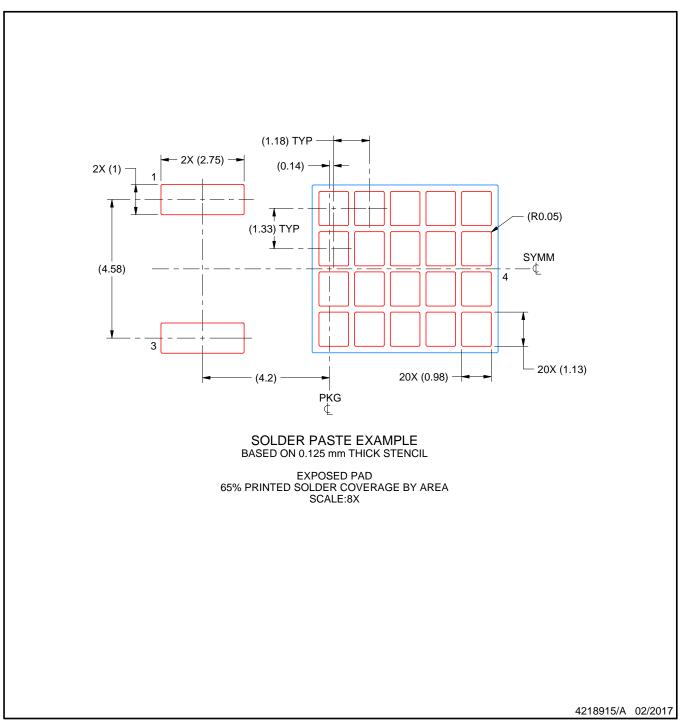




NOTES: (continued)

- 5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
- 6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

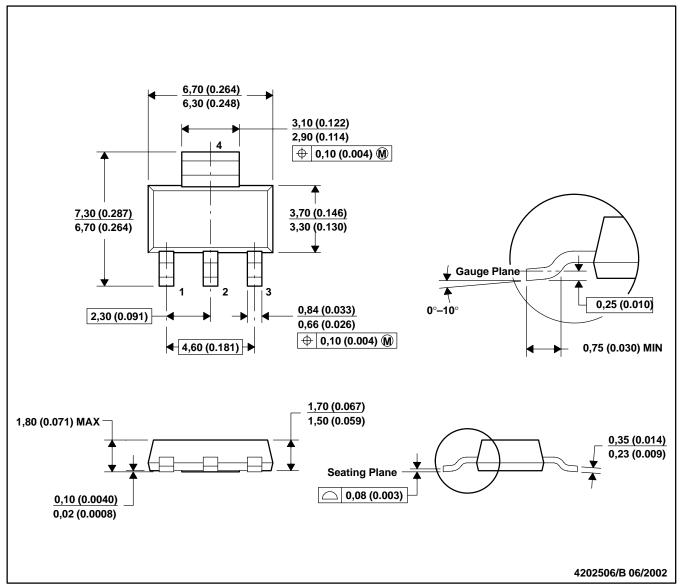
- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

  8. Board assembly site may have different recommendations for stencil design.



#### DCY (R-PDSO-G4)

#### **PLASTIC SMALL-OUTLINE**



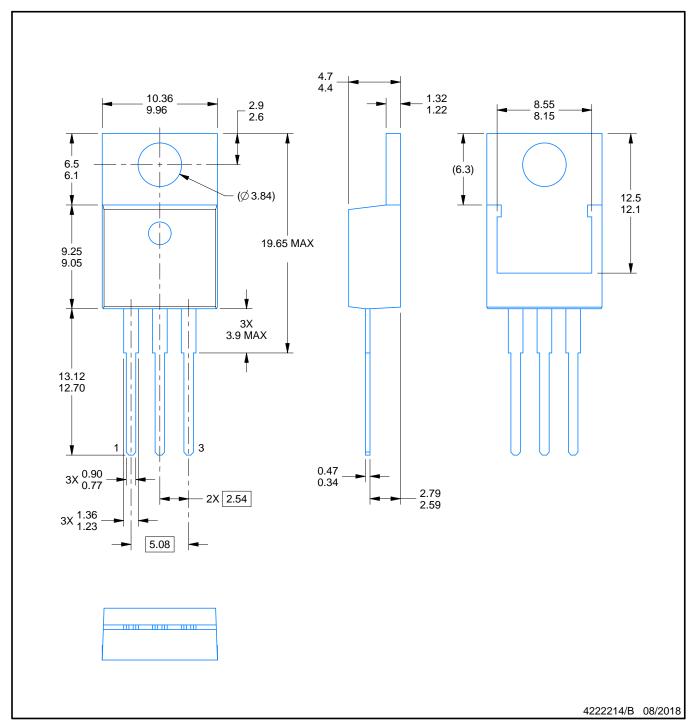
NOTES: A. All linear dimensions are in millimeters (inches).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.

D. Falls within JEDEC TO-261 Variation AA.





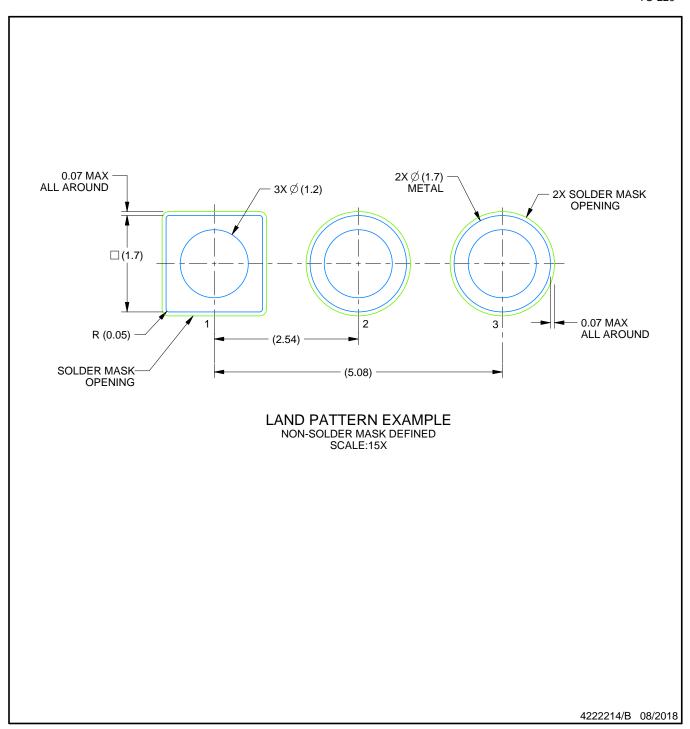
#### NOTES:

- 1. Dimensions are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC registration TO-220.





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